

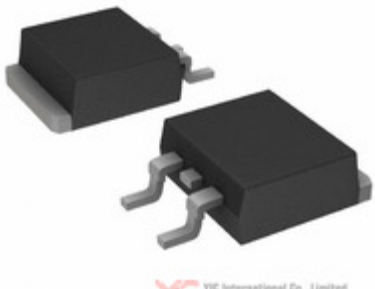


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|  | <h2>SUD50P04-13L-E3</h2> |
| | <p>Hersteller-Teilenummer: SUD50P04-13L-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET P-CH 40V 60A TO252</p> <p>Datenblätter:  SUD50P04-13L-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 20627 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
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| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

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| Teilenummer | SUD50P04-13L-E3 |
| Hersteller | Electro-Films (EFI) / Vishay |
| Beschreibung | MOSFET P-CH 40V 60A TO252 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 20627 pcs Stock |
| detaillierte Beschreibung | P-Channel 40V 60A (Tc) 3W (Ta), 93.7W (Tc) Surface |
| Serie | TrenchFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 175°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | TO-252-3, DPak (2 Leads + Tab), SC-63 |
| Supplier Device-Gehäuse | TO-252, (D-Pak) |
| Verlustleistung (max) | 3W (Ta), 93.7W (Tc) |
| Typ FET | P-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 40V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 60A (Tc) |
| Rds On (Max) @ Id, Vgs | 13 mOhm @ 30A, 10V |
| VGS (th) (Max) @ Id | 3V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 95nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 3120pF @ 25V |
| Antriebsspannung (Max Rds On, Min Rds On) | 4.5V, 10V |
| Vgs (Max) | ±20V |
| Verpackung | Tape & Reel (TR) |
| Bleifreier Status / RoHS-Status | Lead free / RoHS Compliant |
| Feuchtigkeitsempfindlichkeitsniveau (MSL) | 1 (Unlimited) |
| Andere Namen | SUD50P04-13L-E3-ND |

SUD50P04-13L-E3 ist neu im Original, Suche SUD50P04-13L-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SUD50P04-13L-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SUD50P04-13L-E3: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|--|--|--|---|
|  <p>SUD50P04-09L-E3 Vishay / Siliconix MOSFET P-CH 40V 50A TO252</p> |  <p>SUD50P04-13L-GE3 Vishay / Siliconix MOSFET P-CH 40V 60A DPAK</p> |  <p>SUD50P04-13 VISHAY VISHAY SOT252</p> |  <p>SUD50P04-09L-GE3 Vishay Precision Group SUD50P04-09L-GE3 VISHAY</p> |
|  <p>SUD50P04-13L-E3 Vishay / Siliconix MOSFET P-CH 40V 60A TO252</p> |  <p>SUD50P04-13L-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 40V 60A DPAK</p> |  <p>SUD50P04-15-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 40V 50A TO252</p> |  <p>SUD50P04-15 VISHAY SUD50P04-15 VISHAY</p> |

heiße Teile

Mehr

| | | | | |
|----------------------|--------------------|----------------------|-------------------|---------------------|
| ⊛ SUD50N06-07L-GE3 | ↔ SUD50N06-07L-GE3 | ⇒ SUD50N06-08H | D SUD50N06-09L | ↔ SUD50N06-09L-E3 |
| ⊣ SUD50N06-09L-E3 | ⊛ SUD50N06-16 | D SUD50N06-36 | ⇒ SUD50N06L-09 | ↔ SUD50N10-18P |
| ⊛ SUD50N10-18P-E3 | ⊣ SUD50N10-18P-E3 | ⊛ SUD50N10-18P-T4-E3 | ↔ SUD50N10-34P | ↔ SUD50NP04-62-4-E3 |
| D SUD50NP04-62-T4-E3 | ⊛ SUD50NP04-77P | ⊣ SUD50P04-08 | ⊛ SUD50P04-08-GE3 | ↔ SUD50P04-08-GE3 |
| ⇒ SUD50P04-08L | ↔ SUD50P04-09L | ⊛ SUD50P04-09L-E3 | ⊣ SUD50P04-09L-E3 | ↔ SUD50P04-09L-GE3 |
| ↔ SUD50P04-13L-E3 | ⇒ SUD50P04-13L-GE3 | D SUD50P04-13L-GE3 | ⊛ SUD50P04-15-E3 | ⊣ SUD50P04-15-E3 |
| ⊛ SUD50P04-18L | D SUD50P04-23 | ⇒ SUD50P04-23-E3 | ↔ SUD50P04-23-E3 | ↔ SUD50P04-40P |
| ⊣ SUD50P04-40P-E3 | ⊛ SUD50P06-15 | ↔ SUD50P06-15L | ⇒ SUD50P06-15L-E3 | ↔ SUD50P06-15L-E3 |
| ⊛ SUD50P08-25L | ⊣ SUD50P08-25L-E3 | ⊛ SUD50P08-25L-E3 | D SUD50P08-26-E3 | ↔ SUD50P08-26-E3 |
| ↔ SUD50P10-43L | ⊛ SUD50P10-43L-GE3 | ⊣ SUD50P10-43L-GE3 | ⊛ SUD70N02-03P | ↔ SUD70N02-04P |

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